

# Two-output Class E Isolated dc-dc Converter at 5 MHz Switching Frequency<sup>1</sup>

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**Abstract-** This paper presents a two output class-E isolated dc-dc converter that regulates the output voltages at fixed switching frequency. The converter is simulated at operating frequency of 5 MHz. The converter output power is 40 W and the output voltages are 15 V and 5 V. All the switches operate at zero voltage switching (ZVS) conditions for the full load range. The circuit configuration is simple with small passive components which reduce the size of the converter. The circuit also has very good cross-regulation and an inherent short circuit protection with preserved ZVS conditions.

## I. INTRODUCTION

Using high switching frequencies leads to a significant reduction of size of passive components. However, very fast voltage and current transitions mean increasing influence of the layout, the interconnections and packaging on the circuit behavior. Semiconductor devices are exposed to very high di/dt during commutations because of the energy stored in their parasitics which increase switching losses and electromagnetic interference and may cause breakdown of the device. Parasitic inductances and capacitances cause significant problems as the frequency of the circuit is increased. To address these problems in the design of high-frequency operating dc-dc converters topologies that incorporates these parasitics into circuit elements are to be used.

The class-E resonant inverter topology, [1]-[5], addresses these problems which allow its operation in the megahertz order frequencies with zero-voltage switching and zero-voltage slope at turn-on if the switching conditions are met. The class-E topology also absorbs the power MOSFET's parasitic capacitors into the circuit elements and can be implemented with few components. These characteristics, in theory, allow achieving high power densities and high efficiency and reduce the size and weight of the converter.

Since class-E inverter can operate at very high frequency and very high conversion efficiency it can be used in designing resonant dc-dc converters [6]-[10]. The isolated dc-dc converter shown in Figure 1, [11], [12], regulates the output voltage by controlling the conduction time of the auxiliary switch in the rectifier stage connected at the secondary side of the transformer. Based on this concept, in this paper we analyze the extension of this topology to the multiple output power supply, Figure 2.

Each rectifier at the transformer's secondary side has its own controller so all of the output voltages can be regulated for the entire load range variations and the input line voltage variations.

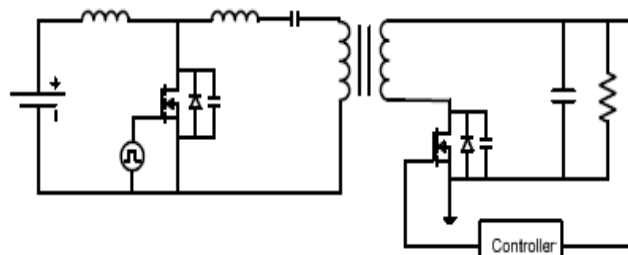


Figure 1: The class-E isolated dc-dc converter

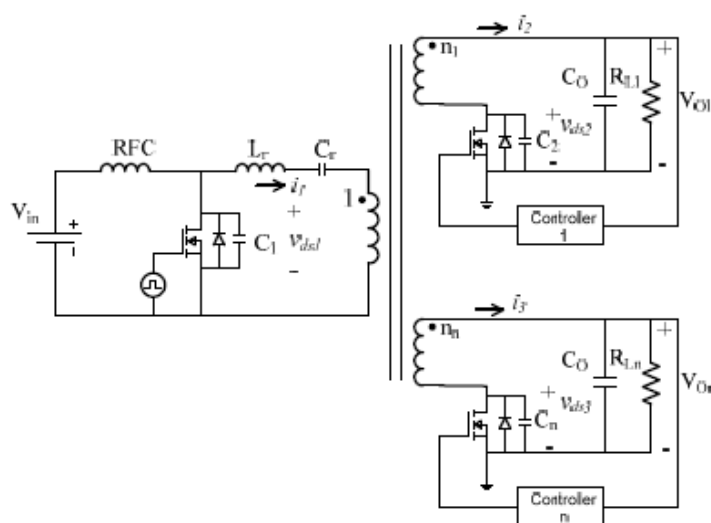


Figure 2: Multiple output class-E isolated dc-dc converter

The analysis and evaluation of the impact that very high switching frequency has in multiple output power supplies is of special interest in the satellite applications. The launch cost is very high and there is a permanent interest in efficiency improvement and in the reduction of the mass and volume of the satellite's equipment. High efficiency operation is important, especially since the primary power source of a satellite is a solar array and batteries, which contributes significantly to the total mass, volume and cost of the satellite. Switching at such a high frequency reduces significantly the size of the converter but can increase the switching losses to an unacceptable level. In this sense, it is important to analyze topologies different to those one

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used for lower frequencies (hundreds of kHz), [13]-[16]. Here, the multiple output converter, shown in Figure 2, is designed and validated with PSpice simulation results.

## II. CIRCUIT DESCRIPTION

The multiple output class-E dc-dc converter shown in Figure 2 consists of a class-E series resonant inverter at the primary side of a high frequency transformer and the controllable synchronous rectifiers at its secondary sides. The class-E inverter consists of an RF choke that injects a dc current into transistor's drain node, the switching transistor with a shunt capacitor and a series resonant tank with a high quality factor,  $Q$ , that makes the resonant tank current approximately sinusoidal. The transistor is driven with the signal at fixed switching frequency and fixed duty cycle. Zero voltage switching conditions, ZVS, are satisfied in both turn-on and turn-off and in the entire range of operation, from-full load to open-circuit.

All the synchronous rectifier stages consist of one secondary winding of the transformer, the switching transistor with its parallel capacitor and the filter formed by the output capacitor and the load. Figure 3 shows the rectifier model where the secondary winding is replaced with two current sources which represent the dc output current, that is magnetizing current  $I_M$ , and the rectifier driving current,  $i_{AC}$ . The principle of operation of the rectifier can be explained from the Figure 4. The duty cycle  $D$  of the controlled switch is changing in the range of  $D_{min} \leq D \leq D_{max}$  in order to regulate the output power at the desired level. When the transistor is off, the negative secondary current charges the parallel capacitor and the voltage  $V_{DS}$  increases. The positive current discharges this capacitor, its voltage decrease, and in the moment when its voltage passes through zero the transistor is turned on. The averaged value of the voltage  $V_{DS}$  is the output voltage since the averaged value of the transformer's secondary winding is zero. A change in the load resistance means changes in the output current  $I_M$  and that leads to different negative peak of the transformer's secondary current and its conduction angle. The duty cycle  $D$  has to be changed to maintain the desired output power. The minimum value  $D_{min}$  correspond to maximum output power when all the negative current is charging the shunt capacitor.

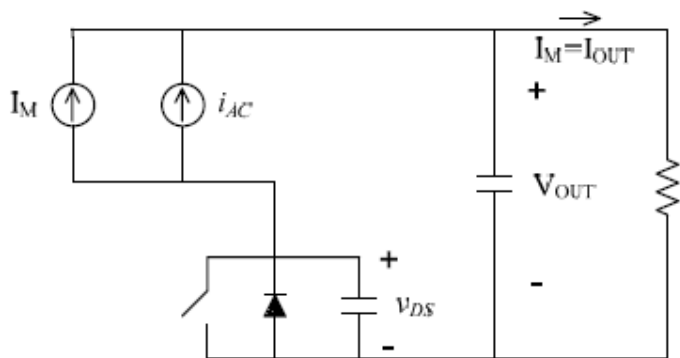


Figure 3: Synchronous rectifier model

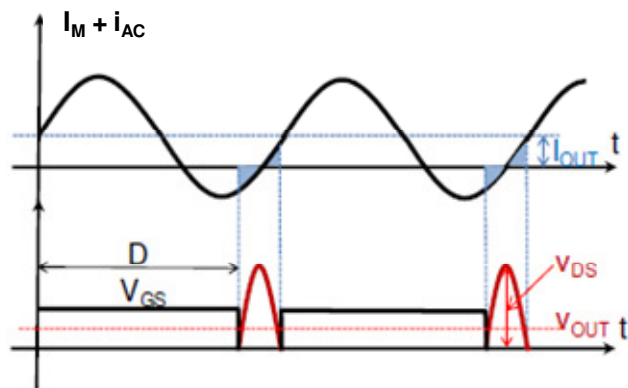


Figure 4: The waveforms of transformer's secondary current, switch driving signal and drain-to source voltage

## III. DESIGN PROCEDURE

A detailed analysis of the synchronous rectifier is given in [8]. Here, the design procedure will be explained briefly for a two output class-E isolated dc-dc converter with the specifications given in Table 1:

Table 1: Converter's specifications

Parameter	Symbol	Value
Input voltage	$V_{in}$	22 – 35 V
Output voltage 1	$V_{OUT1}$	15 V
Output current 1	$I_{OUT1}$	2 A
Output voltage 2	$V_{OUT2}$	5 V
Output current 2	$I_{OUT2}$	2 A
Switching Frequency	$f_{sw}$	5 MHz

The design of the converter is conducted for the minimal value of the input voltage because the circulating currents are the lowest in that case. The fixed duty cycle for the inverter's switch is 0.5 as well as  $D_{min}$  for both the rectifiers. This value is normally selected as a trade-off between the transistor's drain-to-source voltage and the circulating current for the inverter as well as for the rectifiers, Figure 5.

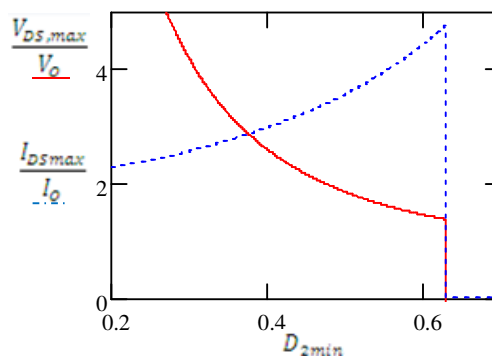


Figure 5: Synchronous rectifiers' transistor current and voltage stresses

Using [8] and the minimum load resistance for both the stages,  $R_{L1}$  and  $R_{L2}$ , needed for nominal output voltage we obtained the parallel capacitors values of  $C_2$  and  $C_3$  as the function of selected  $D_{min}$  from the equation:

$$wC_2R_{Lmin} = \frac{1}{4\pi\sin^2 4\pi D_{min}} \cdot \{(2\pi - 2\pi D_{min})(2\sin 4\pi D_{min} + 4\sin 2\pi D_{min}) + 2(2\pi - 2\pi D_{min})^2(1 + \cos 2\pi D_{min}) - ((2\pi - 2\pi D_{min})^2 - 4)\sin^2 2\pi D_{min}\}$$

Now the input impedances of the rectifiers can be calculated using the describing function method as the RC series network seen at the fundamental harmonic. The turn ratio,  $n_1/n_2$ , is obtained from the relation between the transformer's voltages:

$$v_{prim} = \frac{Z_{rc2} \cdot i_2}{n_1} = \frac{Z_{rc3} \cdot i_3}{n_2}$$

where the  $v_{prim}$  is the fundamental harmonic of the transformer's primary side voltage,  $Z_{rc2}$  and  $Z_{rc3}$  are the respective input impedances of the synchronous rectifiers and  $i_2$  and  $i_3$  are the rectifiers' driving current. The amplitudes of  $i_2$  and  $i_3$  are the same since that are the output currents and duty cycles, so the ratio  $n_1/n_2$  is:

$$\frac{n_1}{n_2} = \frac{Z_{rc2}}{Z_{rc3}}$$

The values for  $n_1$  and  $n_2$  are obtained in order to minimize the inverter's circulating current,  $i_1$ :

$$i_1 = n_1 \cdot i_2 + n_2 \cdot i_3$$

To design class-E inverter we used [2], [3] and the values for the resonant tank elements  $L_r$  and  $C_r$  and shunt capacitance  $C_1$  were obtained. The resonant tank capacitance  $C_r$  in series combination with the transformer's input capacitance makes the class-E inverter resonate with ZVS conditions. Loaded quality factor (Q) for the resonant tank network was selected to be high so the current through the tank was approximately sinusoidal although ZVS for all the switches can be satisfied with lower Q factor. The values for all the components are summarized in Table 2.

Table 2: Converter components values

Component	Symbol	Value
Minimal load resistance 1	$R_{L1}$	2.5 $\Omega$
Minimal load resistance 2	$R_{L2}$	7.5 $\Omega$
Resonant inductor	$L_r$	1.13 $\mu\text{H}$
Resonant capacitor	$C_r$	2.1 nF
Parallel capacitor 1	$C_1$	1 nF
Parallel capacitor 2	$C_2$	4 nF
Parallel capacitor 3	$C_3$	1.4 nF
Transformer's turn ratio	1: $n_1$ : $n_2$	1:0.75:0.25
Output filter capacitor	$C_O$	10 $\mu\text{F}$
Choke	RFC	6 $\mu\text{H}$

#### IV. DESIGN OF THE MAGNETIC COMPONENTS

The design of the inductors and the transformer is critical for the desirable operation of the converter. The circuit is strongly influenced by the parasitic components of the magnetics at the

operating frequency. The design and optimization of these components is conducted by the help of the PEmag finite element analysis (FEA) based tool and the resulting configurations are given in the following paragraphs.

##### a) Choke

The choke inductor acts as a current source in the class E inverter and has a very small current swing. Two possible designs of the input choke are given in Figure 6 and both have the same EP7 – 4F1 core from Ferroxcube and the gap of 16  $\mu\text{m}$  (can't be observed in Figure 6) with the difference in winding strategy. The inductor on the left side of Figure 6 has 10 turns of AWG29 wire and two parallel windings while the inductor on the right side has 4 parallel windings of 10 planar conductor turns. The design with round wire has higher dc and ac resistances of the windings (29 m $\Omega$  and 283 m $\Omega$ ) comparing to the design with planar conductors (22 m $\Omega$  and 157 m $\Omega$ ) which also has the clear possibility to be integrated in the printed circuit board (PCB). The choke inductance value is 6.5  $\mu\text{H}$ .

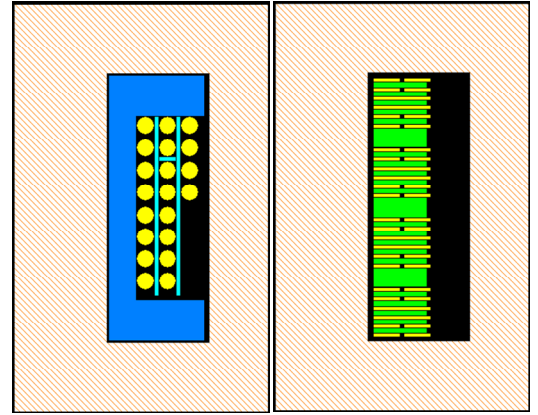


Figure 6: Two possible designs of the input choke

##### b) Resonant inductor

The high circulating current of the resonant tank inductor makes it impossible to be implemented with the reasonable size of the magnetic core. The selected way to build it is to use air core inductor. At 5MHz switching frequency the ac resistance of the resonant air core inductor ( $L_r=1.13 \mu\text{H}$ ) is unacceptable large so the resonant tank network have to be designed with lower Q factor. The lowest value for the resonant tank inductor is obtained when the impedance of the tank network is almost equal to the impedance of the resonant inductor. This means that the resonant capacitor should be increased in order to be seen as a short circuit at the operating frequency. The new values for the resonant inductor and capacitor are  $L_r=450 \text{ nH}$  and  $C_r=70 \text{ nF}$ . The resonant inductor is built as a solenoid with 7 turns of AWG22 wire on a 1 cm diameter core and has a 140 m $\Omega$  of ac resistance. The change in the resonant tank design has no influence on the nominal operating conditions of the converter. However, when the load is changed, the current that circulates through the tank is no longer a sinusoidal as it is at nominal load but has significant harmonic content. These currents increase power losses in the resonant inductor and the transformer since the ac resistance of the windings at the harmonic frequencies is significantly higher than at the fundamental frequency. In order to reduce this effect a small

second harmonic LC filter is added in series with the resonant tank. The filter inductor and capacitor values are  $L_{2f}=30$  nH and  $C_{2f}=8.44$  nF.

c) Transformer

The transformer is designed with 8:6:2 turn ratio on EP13-4F1 core from Ferroxcube. Several winding strategies have been considered in order to minimize the ac resistance of the windings. In Figure 7, two winding strategies with different number of layers and turns per layer are shown. The design on the left side of the Figure 7 has much higher ac resistance in primary and first secondary winding comparing to the design on the right side. The second one is more complicated to integrate in PCB due to the higher number of layers but since it has lower ac resistance of the windings this design is chosen. The ac resistance obtained from PEmag for the primary winding is 80 mΩ and for the secondary windings are 64 mΩ and 23 mΩ (comparing to 127 mΩ, 101 mΩ, 28 mΩ for the left side design). The designs with the round wires have significantly higher ac resistances.

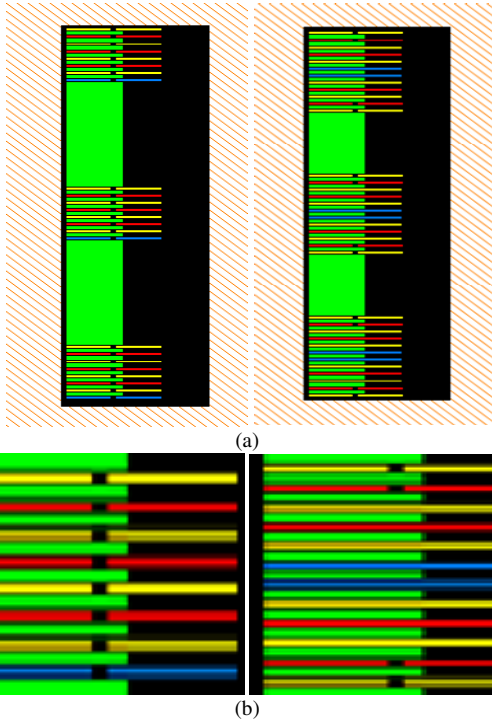


Figure 7: Comparison of transformer's designs: (a) the transformers' structures with 8 primary turns (yellow), 6 first secondary turns (red) and 2 second secondary turns (blue), and (b) detail of the segments replicated 3 times in both structures

V. SIMULATION RESULTS

The two output class-E isolated dc-dc converter was simulated in PSpice circuit simulator using the elements designed in the previous section. An equivalent electrical circuit model for the transformer is obtained in PEmag and is exported to PSpice. The choke and resonant inductors are represented with their inductances in series with dc and ac resistances, respectively. The leakage inductance at the transformer's primary side is included in the simulation and it is absorbed in the resonant tank inductance. For that reason the resonant inductance had to be decreased. The value of the shunt capacitor  $C_1$  was also decreased in order to

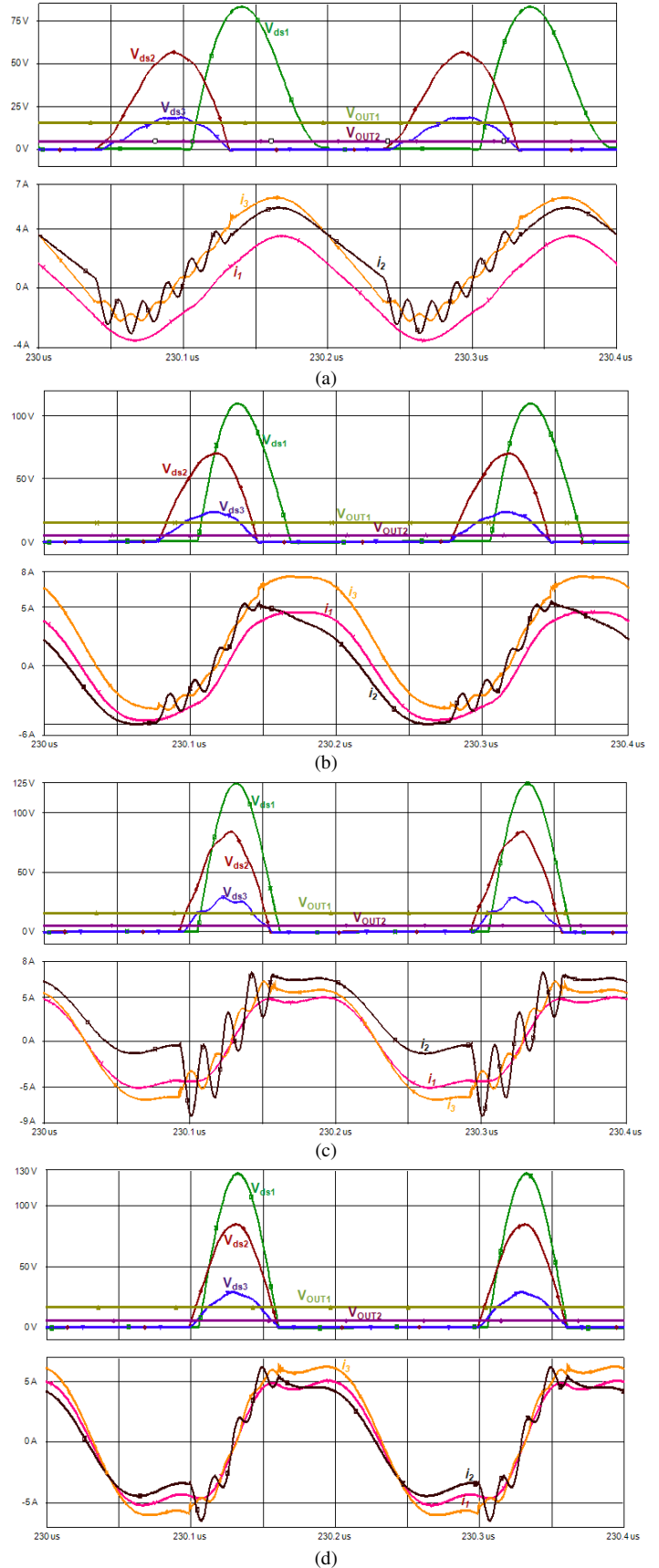


Figure 8: PSpice simulation of the two output converter with different output powers: (a)  $P_{OUT1}=30$  W,  $P_{OUT2}=10$  W, (b)  $P_{OUT1}=30$  W,  $P_{OUT2}=0$  W, (c)  $P_{OUT1}=0$  W,  $P_{OUT2}=10$  W, and (d)  $P_{OUT1}=0$  W,  $P_{OUT2}=0$  W.

attain full ZVS condition in the inverter's switch. The new values for those elements are  $L_r=420$  nH and  $C_1=740$  pF. Figure 8 shows the voltages across the switches  $v_{ds1}$ ,  $v_{ds2}$ ,  $v_{ds3}$ , the output voltages  $V_{OUT1}$  and  $V_{OUT2}$ , and the transformer's currents  $i_1$ ,  $i_2$ ,  $i_3$  at different loads. The figure reveals that all the switches are turned at ZVS conditions for the full-load to open-circuit. It can be observed from Figure 8 that the circulating current  $i_j$  has higher harmonic content when the load is changing. When the output is open-load the value of the third harmonic reaches 1 A which further affects the losses. The driving signals for both the rectifiers are the same which means that the circuit has very good cross regulation and only one control circuit can be implemented for both rectifiers. The maximum variation of  $V_{OUT1}$  is +4 % when the  $V_{OUT2}$  is fixed to its nominal value. The output voltages can also be independently adjusted to the nominal values with slight difference in duty cycles of the gating signals. The losses distribution for the switches and the magnetic elements is given in the Table 3 for the minimal input voltage and full-load. The converter's efficiency is 92 % in this case. When the converter operates under the same conditions as in the Figure 8a and 8b the efficiency decrease to 82 % and 54 %, respectively, while for the open-circuit in the load the power losses are 9.2 W. The converter's efficiency is high at nominal input voltage and nominal load. When the input voltage is increased, the circulating currents are higher and it strongly affects the efficiency out of the nominal operating conditions.

Table 3: Power losses distribution in the converter

Component	Losses
Choke	0.15 W
Switch 1	0.75 W
Resonant inductor	0.85 W
Transformer	1 W
Switch 2	0.33 W
Switch 3	0.27 W

The circuit also has inherent short circuit self protection as can be seen on the Figure 9 in the case of short circuit in one stage or in both stages. The ZVS condition of the inverter switch at turn on and off is preserved even in this case. The power losses in both cases are approximately 1.3 W.

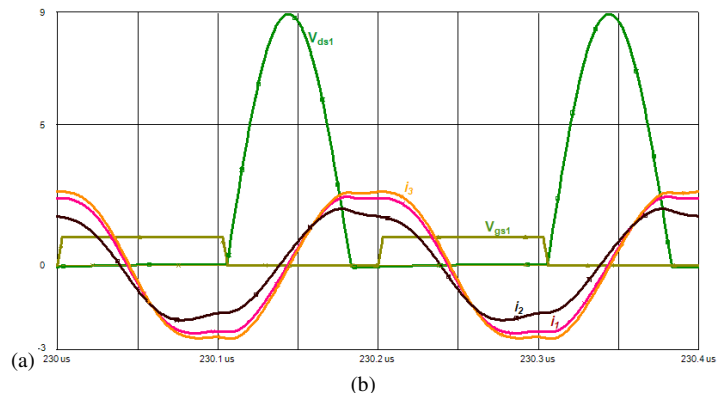


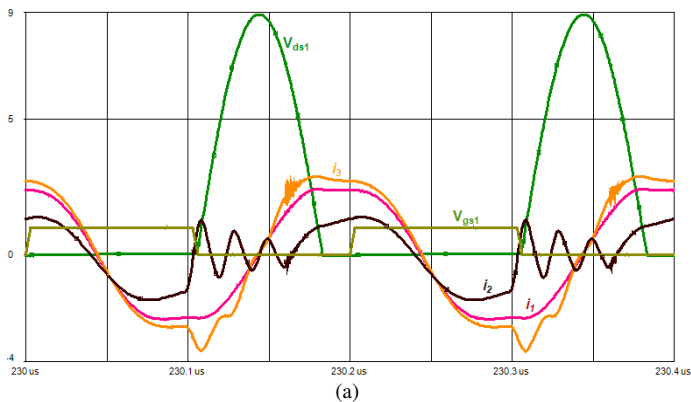
Figure 9: PSpice simulation of Figure 2 with two outputs in case of short circuit at one output (a) and at two outputs (b)

## VI. CONCLUSION

The class E isolated dc/dc converter with two outputs was simulated and the simulation results show that this circuit can work with ZVS conditions in all the transistors and in the entire range of load. One of the advantages of this converter is the very good cross regulation which reduces the number of control circuits at the secondary side of the transformer. The converter has inherent short circuit protection and the inverter's switch operates at ZVS condition even in this case. The class E inverter operates at fixed frequency and fixed duty cycle so the gate driver can be built in the form of resonant circuit which means lower losses in the converter. The drawback of this topology is a poor efficiency when the input voltage is changed from its nominal value.

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